# **FULL-PACK TRIACS**

Glass-passivated 16 ampere triacs in SOT-186 envelopes, which feature an electrically isolated mounting base. They are intended for use in applications requiring high bidirectional transient and blocking voltage capability. Typical applications include AC power control circuits such as lighting, industrial and domestic heating, motor control and switching systems.

## **QUICK REFERENCE DATA**

		BT139F	-500	600	700	800	
Repetitive peak off-state voltage	$v_{DRM}$	max.	500	600	700	800	٧
RMS on-state current	IT(RMS)	max.			16		Α
Non-repetitive peak on-state current at 50 Hz at 60 Hz	ITSM ITSM	max. max.			40 50		A A

# **MECHANICAL DATA**

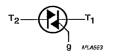
Dimensions in mm

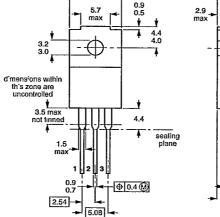
Fig.1 SOT-186

### Pinning:

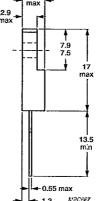
1 = Terminal 1 2 = Terminal 2

3 = Gate





10 2 max



Net mass: 2 g.

The mounting base is electrically isolated from all terminals.

Accessories supplied on request (see data sheets Mounting instructions for F-pack devices and

Accessories for SOT-186 envelopes).

March 1993

## **RATINGS**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

Voltages (in either direction)		BT139F	-500	600	l 700	1800	
Non-repetitive peak off-state voltage (t ≤ 10 ms)	V <sub>DSM</sub>	max.	500*	600*			٧
Repetitive peak off-state voltage $(\delta \le 0.01)$	V <sub>DRM</sub>	max.	500	600	700	800	V
Crest working off-state voltage	$v_{DWM}$	max.	400	400	400	400	V
Currents (in either direction)							
RMS on-state current (conduction angle $360^{\circ}$ ) up to $T_h = 67^{\circ}C$	IT(RMS)	max.		16	3		Α
Repetitive peak on-state current	TRM	max.		140	)		Α
Non-repetitive peak on-state current; $T_j = 120$ °C prior to surge; full sinewave t = 20 ms t = 16.7 ms	ITSM	max. max.		140 150			A A
$I^2$ t for fusing (t = 10 ms)	l²t	max.		98	ŏ		A²s
Rate of rise of on-state current after triggering with I <sub>G</sub> = 200 mA to I <sub>T</sub> = 20 A; $dI_G/dt = 0.2 A/\mu s$	dl <sub>T</sub> /dt	max.		30	)		A/μs
Gate to terminal 1							
Power dissipation							
Average power dissipation (averaged over any 20 ms period) Peak power dissipation	PG(AV)	max.		0.5 5.0			w w
·	PGM	max.		5,0	,		vv
Temperatures -							
Storage temperature	$T_{stg}$		-40 ·	to +125			oC.
Full-cycle operating temperature	Τj	max.		120	)		оС
ISOLATION							
From all three terminals to external heatsink (peak)**	V <sub>(isol)M</sub>	min,		1500	)		V
Capacitance from T <sub>2</sub> to external heatsink	C <sub>(isol)</sub>	typ.		12	2		рF

<sup>\*</sup>Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch into the on-state. The rate of rise of on-state current should not exceed 15  $A/\mu s$ .

<sup>\*\*</sup>Measured with relative humidity <65% under clean and dust-free conditions.

### THERMAL RESISTANCE

Heatsink-mounted with clip (see mounting instructions)

Thermal resistance from junction to external heatsink With heatsink compound

Without heatsink compound

R<sub>th j-h</sub> 3.5 K/W R<sub>th i-h</sub> 4.5 K/W

2. Free-air operation

The quoted values of R<sub>th j-a</sub> should be used only when no leads of other dissipating components run to the same tie-point,

Thermal resistance from junction to ambient in free air:

mounted on a printed-circuit board at a = any lead length

R<sub>th j-a</sub>

55 K/W

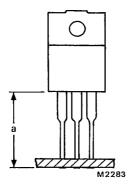


Fig.2

# CHARACTERISTICS (T<sub>i</sub> = 25 °C unless otherwise stated)

Polarities, positive or negative, are identified with respect to T<sub>1</sub>.

# Voltages and currents (in either direction)

On-state voltage (measured	under pulse conditions to pr	event excessive dissipation
I = 20 Δ		V—

1T - 20 A	٧T		1.0	V	
Rate of rise of off-state voltage that will not trigger					
any device; T <sub>i</sub> = 120 <sup>o</sup> C; gate open circuit					
BT139F series	dV <sub>D</sub> /dt	<	100	V/μs	
BT 139F series G	dV <mark>D</mark> /dt	<	200	V/μs	
BT139F series F	dV <mark>D</mark> /dt	<	50	V/μs	
BT139F series F	dΛ ≃ \qt	tvn.	50	Vlus	

Rate of change of commutating voltage that will not trigger any device when  $-dl_{com}/dt = 7.2 \text{ A/ms}$ ;

 $I_{T(RMS)}$  = 16 A;  $T_h$  = 70 °C; gate open circuit;

BT139F series G BT139F series F

 $V_D = V_{DWMmax}$ BT139F series

V/μs Off-state current  $V_D = V_{DWMmax}$ ;  $T_i = 120$  °C; 0.5 mΑ < l<sub>D</sub>

Gate voltage that will trigger all devices Gate voltage that will not trigger any device

 $V_D = V_{DWMmax}$ ;  $T_i = 120 \, {}^{\circ}C$ T<sub>2</sub> and G positive or negative

Gate current that will trigger all devices (IGT); G to T1

Holding current (I <sub>H</sub> )	
-----------------------------------	--

Holding current (I <sub>H</sub> )
-----------------------------------

Latching current ( $I_L$ ); $V_D = 12 V$	
	_

<sup>I</sup>GT BT139F series

lΗ

١L IGT Ιн

1L <sup>I</sup>GT ۱H

BT139F series F

T<sub>2</sub>+

G+

35

30

40

50

60

60

25

30

40

10

30

30

<

<

>

<

<

>

<

<

>

<

<

١L

<sup>I</sup>GT

ΙH

35

30

60

dV<sub>com</sub>/dt typ. 10 dV<sub>com</sub>/dt 10 < dV<sub>com</sub>/dt 10 typ.

1.5 ٧  $V_{GT}$ 

 $V_{GD}$ 

< 250 mV  $T_2$ +

V/us

V/μs

T<sub>2</sub>-G+

70 35 mΑ 30 30 mΑ 40 60 mΑ

100 50 50 mΑ 60 60 60 mΑ 90 60 90 mΑ 25 70 mΑ 25

30 30 30 mΑ 60 40 60 mΑ 10 10 25 mA

30 30 30 mΑ 40 30 40 mΑ

March 1993 154

BT139F series G

BT139F series E

BT139F SERIES

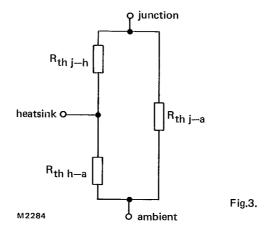
### MOUNTING INSTRUCTIONS

- 1. The triac may be soldered directly into the circuit, but the maximum permissible temperature of the soldering iron or bath is 275 °C; it must not be in contact with the joint for more than 5 seconds. Soldered joints must be at least 4.7 mm from the seal.
- 2. The leads should not be bent less than 2.4 mm from the seal, and should be supported during bending. The leads can be bent, twisted or straightened by 90° maximum. The minimum bending radius is 1 mm.
- 3. Mounting by means of a spring clip is the best mounting method because it offers good thermal contact under the crystal area and slightly lower R<sub>th j-h</sub> values than screw mounting. However, if a screw is used, it should be M3 cross-recess pan-head. Care should be taken to avoid damage to the plastic body.
- 4. For good thermal contact heatsink compound should be used between mounting base and heatsink. Values of Rth i-h given for mounting with heatsink compound refer to the use of a metallic-oxide loaded compound. Ordinary silicone grease is not recommended.
- Rivet mounting is not recommended.
- 6. The heatsink must have a flatness in the mounting area of 0.02 mm maximum per 10 mm. Mounting holes must be deburred.

#### **OPERATING NOTES**

Dissipation and heatsink considerations:

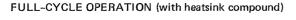
a. The various components of junction temperature rise above ambient are illustrated in Fig.3.



- b. The method of using Figs.4 and 5 is as follows: Starting with the required current on the IT(RMS) axis (I.h. graph) trace upwards to meet the appropriate conduction angle curve. Trace left from curve to obtain power P. Trace right from curve to obtain T<sub>h</sub> (r.h. graph). Trace upwards from T<sub>amb</sub>, intersect with T<sub>h</sub> determines R<sub>th h-a</sub>, required heatsink thermal resistance.
- c. Any measurement of heatsink temperature should be made immediately adjacent to the device.



65E D 📼 7110826 0062323 343 **■**PHIN



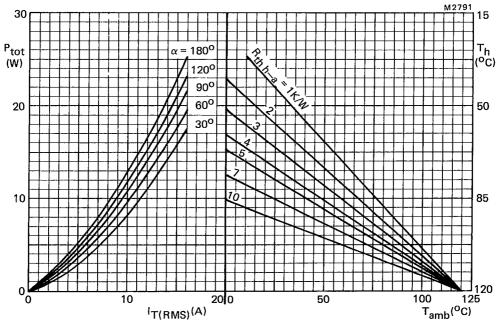


Fig. 4 The right-hand part shows the interrelationship between the power (derived from the left-hand part) and the maximum permissible temperatures.



 $\alpha = \alpha_1 = \alpha_2$ : conduction angle per half cycle

Triacs

65E D

■ 7110826 0062324 28T ■PHIN **BT139F SERIES** 

FULL-WAVE CONDUCTION (without heatsink compound)

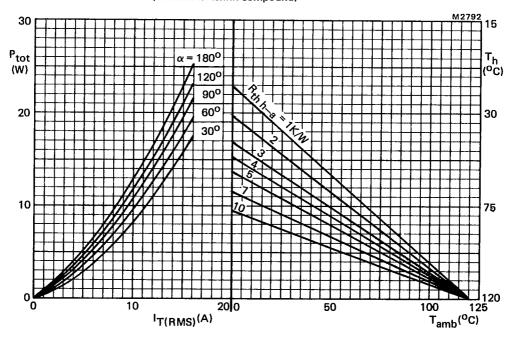


Fig.5 The right-hand part shows the interrelationship between the power (derived from the left-hand part) and the maximum permissible temperatures.

$$\alpha = \alpha_1 = \alpha_2$$
: conduction angle per half cycle

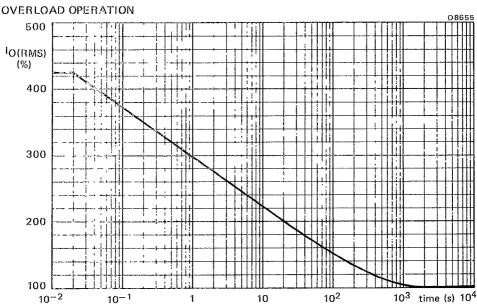


Fig.6 Maximum permissible duration of steady overload (provided that T<sub>mb</sub> does not exceed 120 °C during and after overload) expressed as a percentage of the steady state r.m.s. rated current. For high r.m.s. overload currents precautions should be taken so that the temperature of the terminals does not exceed 125 °C. During these overload conditions the triac may lose control. Therefore the overload should be terminated by a separate protection device.

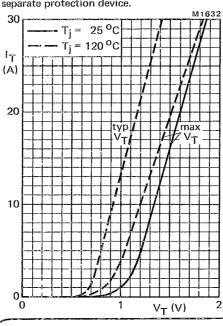
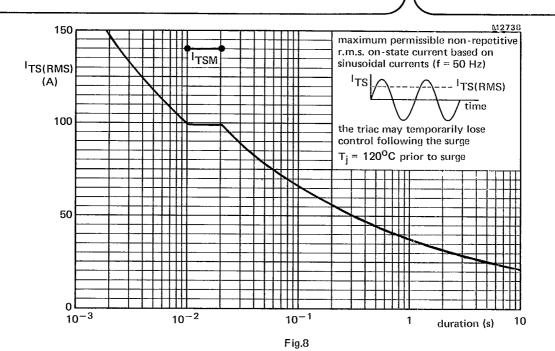


Fig.7

**Triacs** 



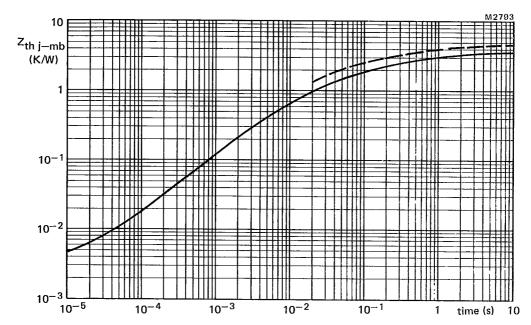


Fig.9 Transient thermal impedance; ——with heatsink compound; — — without heatsink compound.



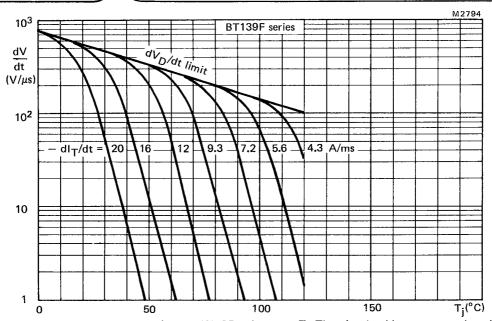


Fig. 10 Typical commutation dV/dt for BT139F series versus  $T_j$ . The triac should commutate when the dV/dt is below the value on the appropriate curve for pre-commutation  $dI_T/dt$ .

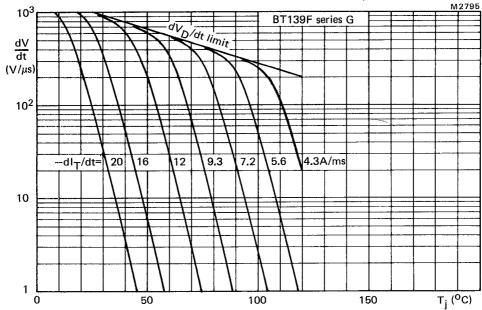


Fig.11 Limit commutation dV/dt for BT139F series G versus  $T_j$ . The triac should commutate when the dV/dt is below the value on the appropriate curve for pre-commutation  $dI_T/dt$ .



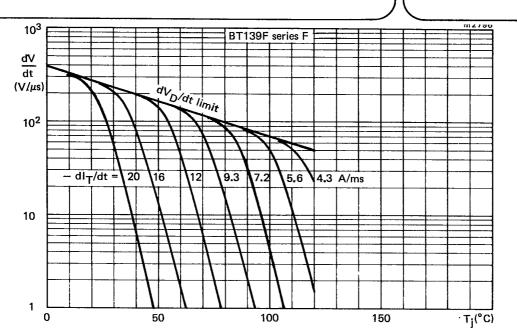


Fig.12 Typical commutation dV/dt for BT139F series F versus  $T_j$ . The triac should commutate when the dV/dt is below the value on the appropriate curve for pre-commutation  $dI_T/dt$ .

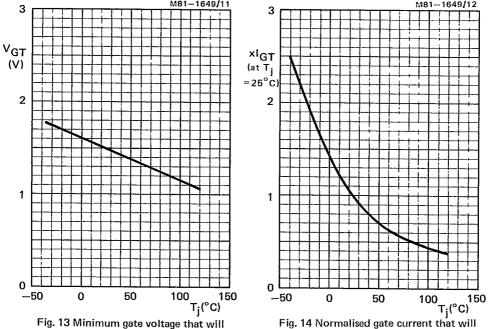


Fig. 13 Minimum gate voltage that will trigger all devices; all conditions.

trigger all devices; all conditions.

March 1993

### LIMITS FOR STARTING OR INRUSH CURRENTS - FULL-CYCLE OPERATION

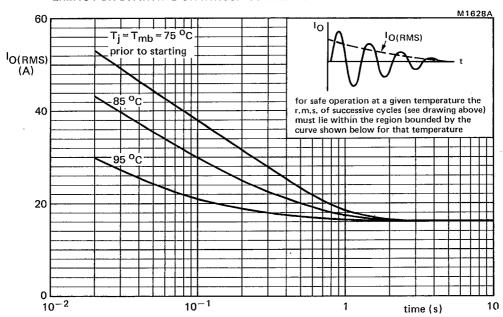


Fig.15.